

ISP621-1X, ISP621-2X, ISP621-4X
ISP621-1, ISP621-2, ISP621-4



**HIGH DENSITY MOUNTING
PHOTOTRANSISTOR
OPTICALLY COUPLED ISOLATORS**

APPROVALS

- UL recognised, File No. E91231
- 'X' SPECIFICATION APPROVALS
 - VDE 0884 in 3 available lead form : -
-STD
- G form
- SMD approved to CECC 00802
 - Certified to EN60950 by the following Test Bodies :-
Nemko - Certificate No. P96102022
Fimko - Registration No. 192313-01..25
Semko - Reference No. 9639052 01
Demko - Reference No. 305969

DESCRIPTION

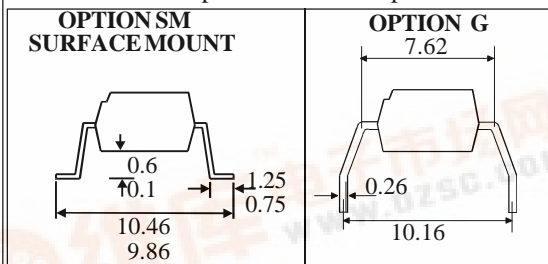
The ISP621-1, ISP621-2, ISP621-4 series of optically coupled isolators consist of infrared light emitting diodes and NPN silicon photo transistors in space efficient dual in line plastic packages.

FEATURES

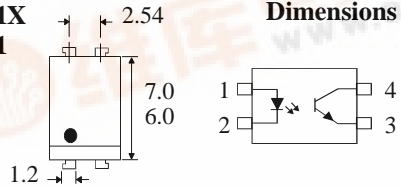
- Options :-
10mm lead spread - add G after part no.
Surface mount - add SM after part no.
Tape&reel - add SMT&R after part no.
- High Current Transfer Ratio (50% min)
- High Isolation Voltage (5.3kV_{RMS}, 7.5kV_{PK})
- High BV_{CEO} (55Vmin)
- All electrical parameters 100% tested
- Custom electrical selections available

APPLICATIONS

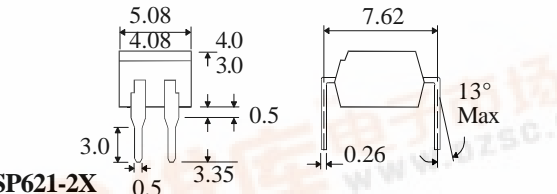
- Computer terminals
- Industrial systems controllers
- Measuring instruments
- Signal transmission between systems of different potentials and impedances



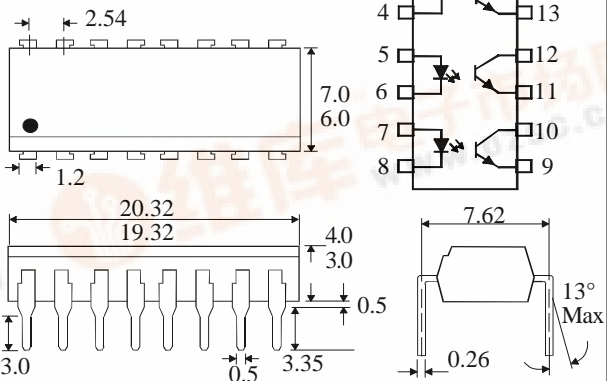
**ISP621-1X
ISP621-1** **Dimensions in mm**



**ISP621-2X
ISP621-2**



**ISP621-4X
ISP621-4**



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ABSOLUTE MAXIMUM RATINGS
(25°C unless otherwise specified)

Storage Temperature	-55°C to + 125°C
Operating Temperature	-55°C to + 100°C
Lead Soldering Temperature (1/16 inch (1.6mm) from case for 10 secs)	260°C

INPUT DIODE

Forward Current	50mA
Reverse Voltage	5V
Power Dissipation	70mW

OUTPUT TRANSISTOR

Collector-emitter Voltage BV_{CEO}	55V
Emitter-collector Voltage BV_{ECO}	6V
Power Dissipation	150mW

POWER DISSIPATION

Total Power Dissipation	200mW
(derate linearly 2.67mW/°C above 25°C)	

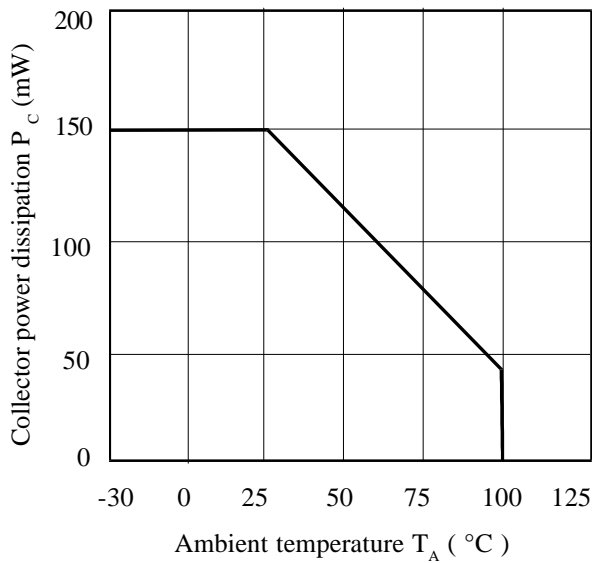
ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F)	1.0	1.15	1.3	V	$I_F = 10\text{mA}$ $I_R = 10\mu\text{A}$ $V_R = 5\text{V}$
	Reverse Voltage (V_R)	5			V	
	Reverse Current (I_R)			10	μA	
Output	Collector-emitter Breakdown (BV_{CEO}) (Note 2)	55			V	$I_C = 0.5\text{mA}$ $I_E = 100\mu\text{A}$ $V_{CE} = 24\text{V}$
	Emitter-collector Breakdown (BV_{ECO})	6			V	
	Collector-emitter Dark Current (I_{CEO})			100	nA	
Coupled	Current Transfer Ratio (CTR) (Note 2) ISP621-1, ISP621-2, ISP621-4	50		600	%	$5\text{mA } I_F, 5\text{V } V_{CE}$ $1\text{mA } I_F, 0.4\text{V } V_{CE}$
	CTR selection available GB	100		600	%	
	BL	200		600	%	
	GB	30			%	
	Collector-emitter Saturation Voltage $V_{CE(SAT)}$ GB			0.4	V	$8\text{mA } I_F, 2.4\text{mA } I_C$ $1\text{mA } I_F, 0.2\text{mA } I_C$
	Input to Output Isolation Voltage V_{ISO}	5300		0.4	V	
		7500			V_{RMS}	See note 1
	Input-output Isolation Resistance R_{ISO}	5×10^{10}			V_{PK}	See note 1
	Rise Time tr		2		μs	$V_{IO} = 500\text{V}$ (note 1) $V_{CC} = 10\text{V}$, $I_C = 2\text{mA}, R_L = 100\Omega$
	Fall Time tf		3		μs	
	Turn-on Time ton		3		μs	
Turn-off Time toff		3		μs		

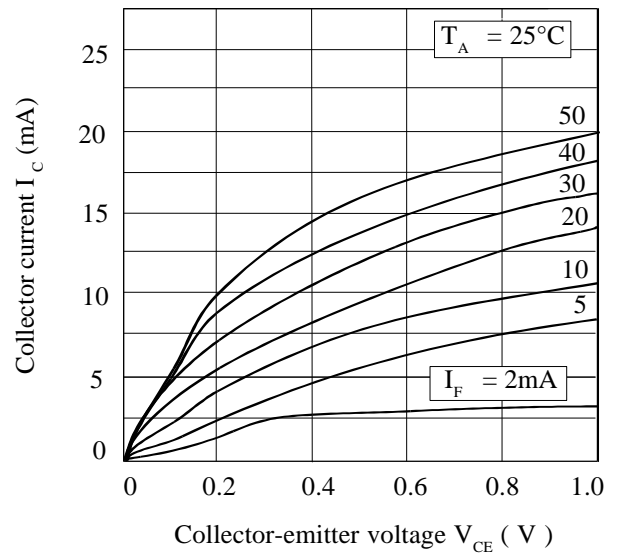
Note 1 Measured with input leads shorted together and output leads shorted together.

Note 2 Special Selections are available on request. Please consult the factory.

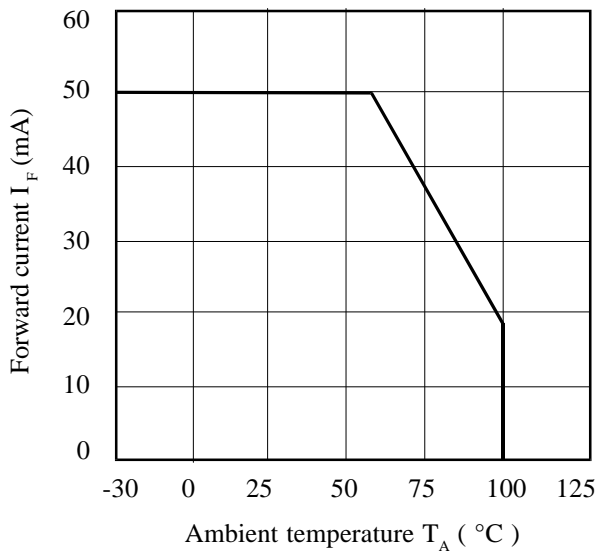
Collector Power Dissipation vs. Ambient Temperature



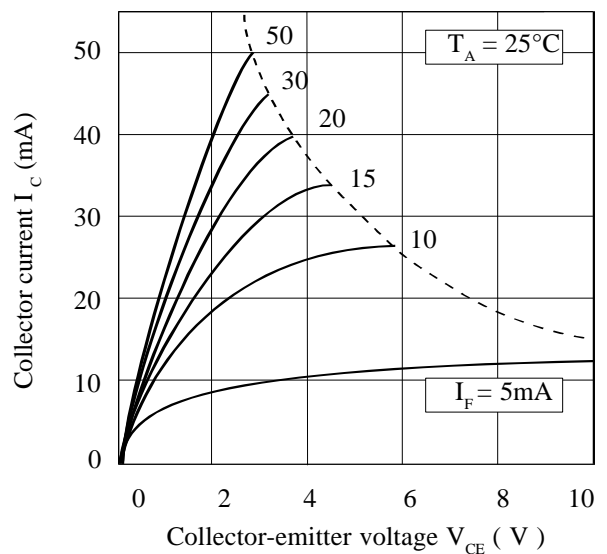
Collector Current vs. Low Collector-emitter Voltage



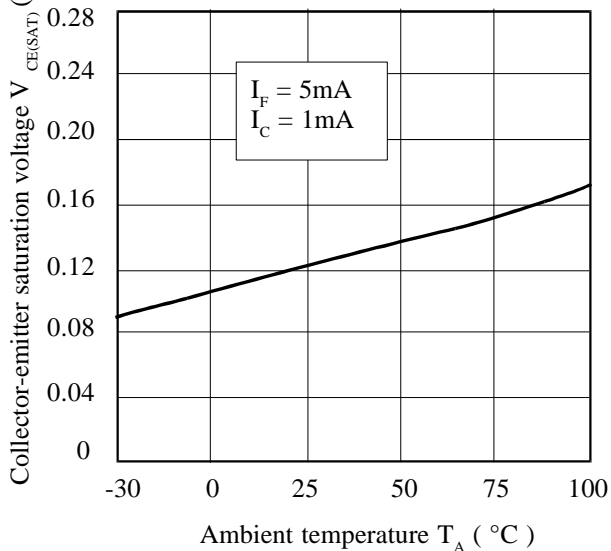
Forward Current vs. Ambient Temperature



Collector Current vs. Collector-emitter Voltage



Collector-emitter Saturation Voltage vs. Ambient Temperature



Current Transfer Ratio vs. Forward Current

